chanhvinh.com

ACNV260E

2mm DTI, 10MBd Digital Optocoupler

Data Sheet

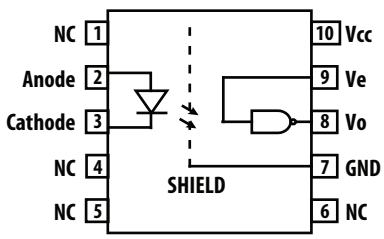
Description

The new ACNV260E is an optically coupled gate that combines a AlGaAs light emitting diode and an integrated photo detector housed in a widebody package. ACNV260E is designed and manufactured to comply with EN60079-11 ATEX and IECEx. The distance-through-insulation (DTI) between the emitting diode and photodetector is at 2mm. The output of the detector IC is an open collector Schottky clamped transistor. The internal shield provides a guaranteed common mode transient immunity specification of 20,000 V/µs at V_{cm} = 1500V

This unique design provides maximum ac and dc circuit isolation while achieving TTL compatibility.

The new ACNV260E is suitable for high speed logic interfacing, input/output buffering, as line receivers in environments that conventional line receivers cannot tolerate and are recommended for use in extremely high ground or induced noise environments.

Functional Diagram



Truth Table (Positive Logic)

LED	ENABLE	OUTPUT
On	H	L
Off	H	H
On	L	H
Off	L	H
On	NC	L
Off	NC	H

A 0.1 µF bypass capacitor must be connected between pins V_{CC} and GND.

Features

- Compliant to EN60079-11 ATEX and IECEx (375V)
- 2mm DTI
- 13mm creepage and clearance
- 20 kV/µs Minimum Common Mode Rejection (CMR) at VCM = 1500 V
- High Speed: 10 MBd Typical
- TTL Compatible
- Guaranteed ac and dc performance over temperature: -40°C to +105°C
- Available in 10-Pin widebody packages
- Safety Approval
  - Approval at 5000 Vrms for 1 minute per UL1577
  - CSA

Applications

- High Voltage insulation
- Intrinsic safety circuit
- PCB Board Power System Isolation
- Industrial Equipment Power Isolation

CAUTION: *It is advised that normal static precautions be taken in handling and assembly of this component to prevent damage and/or degradation which may be induced by ESD.*

chanhvinh.com

Ordering Information

ACNV260E is UL Recognized with 5000 Vrms for 1 minute per UL1577.

Part number	Option RoHS Compliant	Package	Surface Mount	Gull Wing	Tape & Reel	UL 5000 V_{rms} / 1 Minute rating	Quantity
ACNV260E	-000E	500 mil DIP-10				X	35 per tube
	-300E		X	X		X	35 per tube
	-500E		X	X	X	X	500 per reel

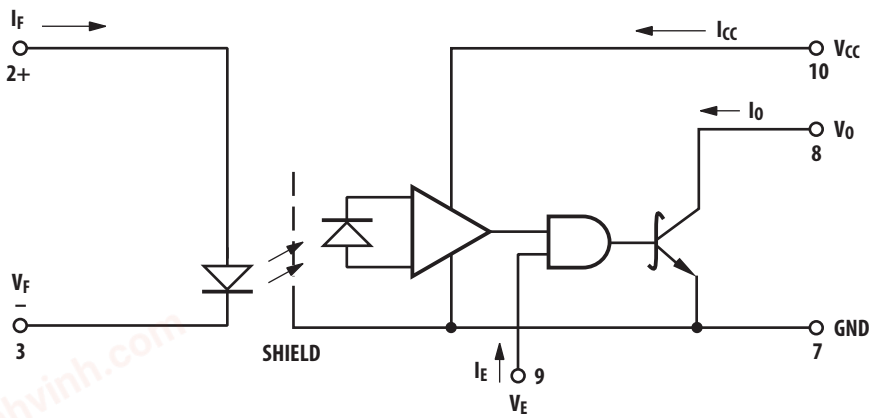
To order, choose a part number from the part number column and combine with the desired option from the option column to form an order entry.

Example 1:

ACNV260E-500E to order product of 500mil DIP-10 Widebody with Gull Wing Surface Mount package in Tape and Reel packaging with UL 5000Vrms/1min Safety Approval in RoHS compliant.

Option datasheets are available. Contact your Avago sales representative or authorized distributor for information.

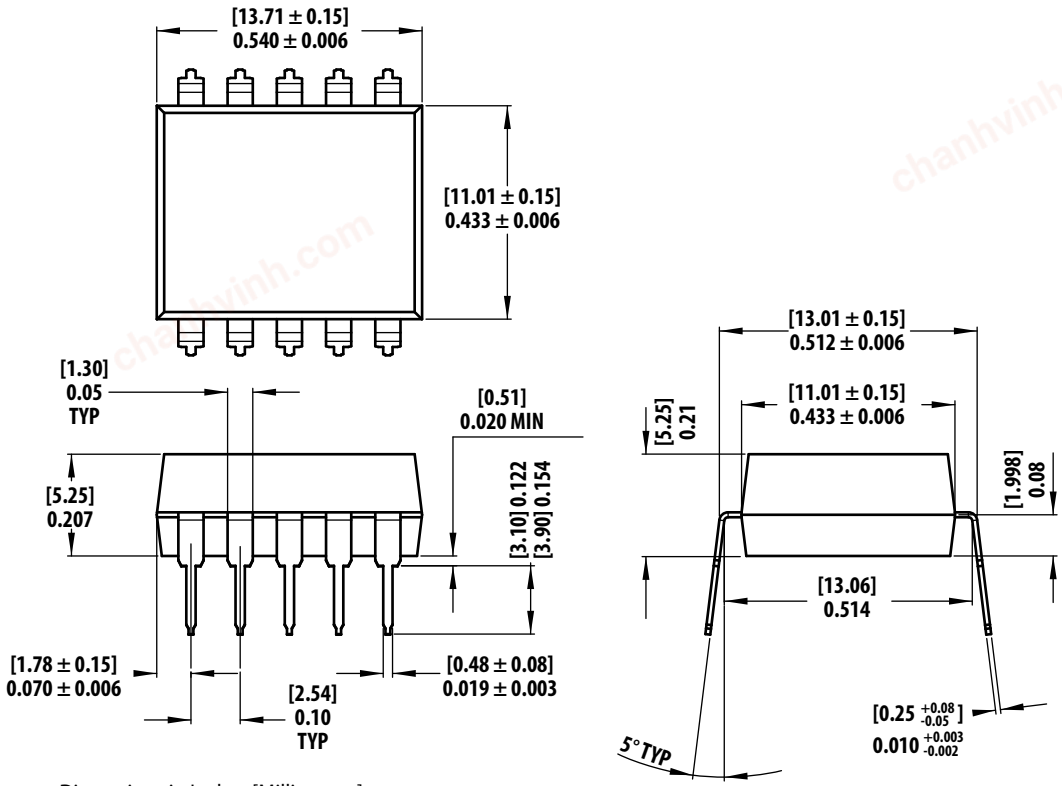
Schematic



Use of a 0.1μF bypass capacitor connected between pins of 7 and 10 is recommended (see note 5).

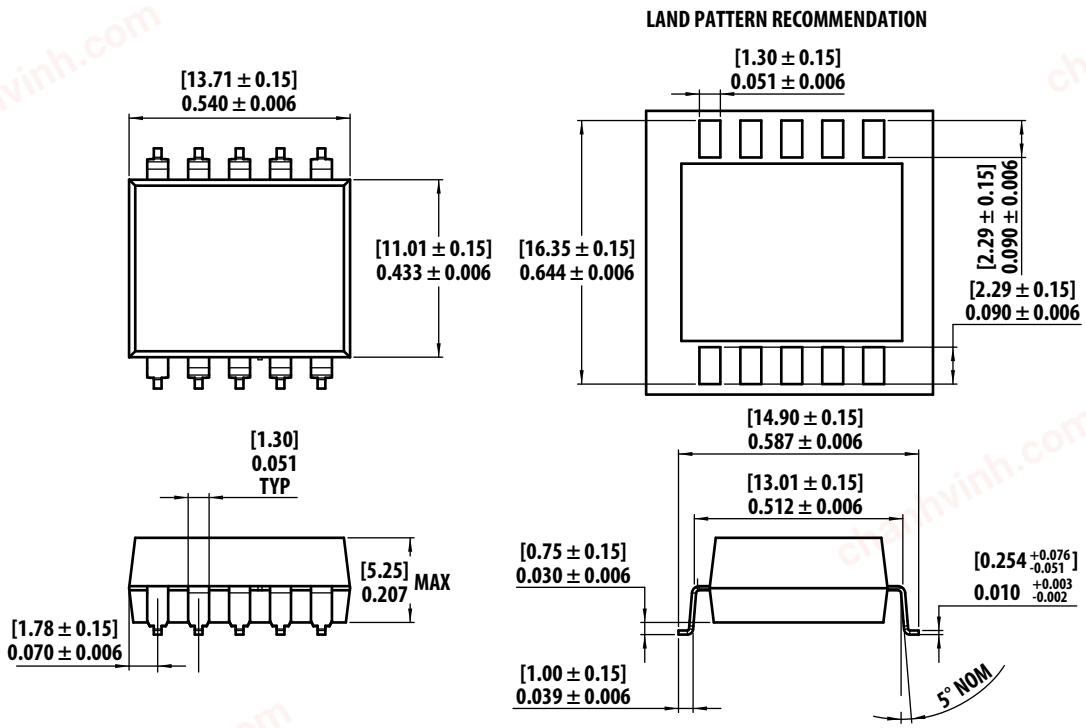
chanhvinh.com

10-Pin Widebody (500mils) DIP Package



Dimensions in Inches [Millimeters]

10-Pin Widebody (500mils) DIP Package with Gull Wing Surface Mount Option 300



Dimension in Inches [Millimeter]

chanhvinh.com

Solder Reflow Profile

Recommended reflow condition as per JEDEC Standard, J-STD-020 (latest revision). Non-Halide Flux should be used.

Insulation and Safety Related Specifications

Parameter	Symbol	ACNV260E	Units	Conditions
Minimum External Air Gap (External Clearance)	L(101)	13	mm	Measured from input terminals to output terminals, shortest distance through air.
Minimum External Tracking (External Creepage)	L(102)	13	mm	Measured from input terminals to output terminals, shortest distance path along body.
Minimum Internal Plastic Gap (Internal Clearance)		2.0	mm	Through insulation distance conductor to conductor, usually the straight line distance thickness between the emitter and detector.
Minimum Internal Tracking (Internal Creepage)		4.6	mm	Measured from input terminals to output terminals, along internal cavity.
Tracking Resistance (Comparative Tracking Index)	CTI	200	V	DIN IEC 112/VDE 0303 Part 1.
Maximum Working Insulation Voltage	V_{IORM}	375	V_{peak}	Per IEC 60079-11.
Safety-limiting values – maximum values allowed in the event of a failure.				
Case Temperature	T_S	150	°C	
Input Current**	$I_{S, INPUT}$	400	mA	
Output Power**	$P_{S, OUTPUT}$	1	W	
Isolation Group		IIIa		Material Group (DIN VDE 0110, 1/89, Table 1).

Note:
** Refer to Figure 14 for dependence of PS and IS on ambient temperature.

Absolute Maximum Ratings

Parameter	Symbol	Min.	Max.	Units
Storage Temperature	T_S	-55	125	°C
Operating Temperature	T_A	-40	105	°C
Average Input Current	$I_{F(AVG)}$		20	mA
Reverse Input Voltage	V_R		3	V
Input Power Dissipation	P_I		40	mW
Supply Voltage (1 Minute Maximum)	V_{CC}		7	V
Enable Input Voltage (Not to Exceed V_{CC} by more than 500mV)	V_E		V_{CC}+0.5	V
Enable Input Current	I_E		5	mA
Output Collector Current	I_O		50	mA
Output Collector Voltage	V_O		7	V
Output Collector Power Dissipation	P_O		85	mW
Lead Solder Temperature	T_{LS}		245°C for 10 sec, up to seat plane	
Solder Reflow Temperature Profile	See Package Outline Drawings section			

chanhvinh.com

Recommended Operating Conditions

Parameter	Symbol	Min.	Max.	Units	Note
Input Current, Low Level	I_{FL}*	0	250	µA	
Input Current, High Level	I_{FH}**	9	16	mA	1
Power Supply Voltage	V_{CC}	4.5	5.5	V	
Low Level Enable Voltage	V_{EL}	0	0.8	V	
High Level Enable Voltage	V_{EH}	2.0	V_{CC}	V	
Operating Temperature	T_A	- 40	105	°C	
Fan Out (at R_L = 1k Ω)	N		5	TTL Loads	
Output Pull-up Resistor	R_L	330	4k	Ω	

* The off condition can also be guaranteed by ensuring that V_{FL} ≤0.8volts.

** The initial switching threshold is 8mA or less. It is recommended that 9mA to 16mA be used for best performance and to permit at least a 20% LED degradation guardband.

Electrical Specifications (DC)

Over recommended operating conditions unless otherwise specified. All typicals at V_{CC} = 5 V, T_A = 25°C.

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
High Level Output Current	I_{OH}		5.5	100	µA	V_{CC} = 5.5 V, V_E = 2.0V V_O = 5.5 V, I_{FL} = 250 µA		12
Input Threshold Current	I_{TH}		3.5	8	mA	V_{CC} = 5.5 V, V_E = 2.0V, V_O = 0.6 V, I_{OL} > 13 mA	1, 2	12
Low Level Output Voltage	V_{OL}		0.35	0.6	V	V_{CC} = 5.5 V, V_E = 2.0V, I_F = 8 mA, $I_{OL(Sinking)}$ = 13 mA	1, 2, 3, 4	12
High Level Supply Current	I_{CCH}		7.0	12	mA	V_E = 0.5V; V_{CC} = 5.5 V, I_F = 0 mA		
			6.5			V_E = V_{CC}		
Low Level Supply Current	I_{CCL}		9.0	13	mA	V_E = 0.5V; V_{CC} = 5.5 V, I_F = 10 mA		
			8.5			V_E = V_{CC}		
High Level Enable Current	I_{EH}		-0.7		mA	V_{CC} = 5.5 V, V_E = 2.0V		
Low Level Enable Current	I_{EL}		-0.9		mA	V_{CC} = 5.5 V, V_E = 0.5V		
High Level Enable Voltage	V_{EH}	2.0			mA	V_{CC} = 5.5 V, V_E = 2.0V		12
Low Level Enable Voltage	V_{EL}			0.8	mA	V_{CC} = 5.5 V, V_E = 0.5V		
Input Forward Voltage	V_F	1.25	1.64	1.85	V	T_A = 25°C; I_F = 10 mA	5	
		1.2		2.05				
Input Reverse Breakdown Voltage	BV_R	5			V	I_R = 100 µA, T_A = 25°C		
Input Capacitance	C_{IN}		60		pF	f = 1 MHz, V_F = 0 V		
Input Diode Temperature Coefficient	$\Delta V_F/\Delta T_A$		-1.9		mV/°C	I_F = 10 mA		

chanhvinh.com

Switching Specifications (AC)

Over recommended temperature (T_A = -40°C to 105°C), V_{CC} = 5 V, I_F = 10mA unless otherwise specified. All typicals are at T_A = 25°C, V_{CC} = 5V.

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
Propagation Delay Time to High Output Level	t_{PLH}	30	50	80 120	ns	T_A = 25°C, R_L = 350Ω, C_L = 15 pF	6, 7, 8	3, 12
Propagation Delay Time to Low Output Level	t_{PHL}	35	55	80 120	ns	T_A = 25°C		4,12
Pulse Width Distortion	$\|t_{PHL} - t_{PLH}\|$		5	40	ns	R_L = 350 Ω, C_L = 15 pF	6, 7, 8, 9	6, 12
Propagation Delay Skew	t_{psk}			50	ns			5, 6, 12
Output Rise Time (10%-90%)	T_r		25		ns		10	12
Output Fall Time (10%-90%)	T_f		10		ns		10	12
Propagation Delay Time of Enable from V_{EH} to V_{EL}	t_{ELH}		30		ns	R_L = 350 Ω, C_L = 15 pF, V_{EL} = 0V, V_{EH} = 3V	11, 12	7
Propagation Delay Time of Enable from V_{EL} to V_{EH}	t_{EHL}		20		ns	R_L = 350 Ω, C_L = 15 pF, V_{EL} = 0V, V_{EH} = 3V	11, 12	8
Output High Level Common Mode Transient Immunity	$\|CM_H\|$	20	25		kV/µs	V_{CC} = 5 V, I_F = 0 mA, $V_{O(MIN)}$ = 2 V, R_L = 350 Ω, T_A = 25°C, V_{CM} = 1500 V	13	9, 11, 12
Output Low Level Common Mode Transient Immunity	$\|CM_L\|$	20	25		kV/µs	V_{CC} = 5 V, I_F = 10 mA, $V_{O(MAX)}$ = 0.8 V, R_L = 350 Ω, T_A = 25°C, V_{CM} = 1500 V		10, 11, 12

Package Characteristics

All typicals at T_A = 25°C.

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions	Fig.	Note
Input-Output Insulation	V_{ISO}	5000			V_{rms}	RH < 50% for 1 min. T_A = 25°C		13, 14
Input-Output Resistance	R_{I-O}	10^{12}			Ω	V_{I-O} = 500 V		13
Input-Output Capacitance	C_{I-O}		0.5	0.6	pF	f = 1 MHz, T_A = 25°C		13

Notes:

1. Peaking circuits may produce transient input currents up to 50mA, 50ns maximum pulse width, provided average current does not exceed 20mA.
2. By passing of power supply line is required, with a 0.1µF ceramic disc capacitor adjacent to each optocoupler as illustrated in Figure 15. Total lead length between both ends of the capacitor and the isolator pins should ot exceed 20mm.
3. The t_{PLH} propagation delay is measured from the 5 mA point on the falling edge of the input pulse to the 1.5 V point on the rising edge of the output pulse.
4. The t_{PHL} propagation delay is measured from the 5 mA point on the rising edge of the input pulse to the 1.5 V point on the falling edge of the output pulse.
5. t_{PSK} is equal to the worst case difference in t_{PHL} and/or t_{PLH} that will be seen between units at any given temperature and specified test conditions.
6. See application section titled "Propagation Delay, Pulse-Width Distortion and Propagation Delay Skew" for more information.
7. The t_{ELH} enable propagation delay is measured from the 1.5 V point on the falling edge of the enable input pulse to the 1.5 V point on the rising edge of the output pulse.
8. The t_{EHL} enable propagation delay is measured from the 1.5 V point on the rising edge of the enable input pulse to the 1.5 V point on the falling edge of the output pulse.
9. CM_H is the maximum tolerable rate of rise of the common mode voltage to assure that the output will remain in a high logic state (i.e., V_O > 2.0 V).
10. CM_L is the maximum tolerable rate of fall of the common mode voltage to assure that the output will remain in a low logic state (i.e., V_O < 0.8 V).
11. For sinusoidal voltages, $(|dV_{CM}| / dt)_{max} = \pi f_{CM} V_{CM(p-p)}$.
12. No external pull up is required for a high logic state on the enable input. If the V_E pin is not used, tying V_E to V_{CC} will result in improved CM_R performance.
13. Device considered a two-terminal device: pins 1, 2, 3, 4 and 5 shorted together, and pins 6, 7, 8, 9 and 10 shorted together.
14. In accordance with UL1577, each optocoupler is proof tested by applying an insulation test voltage ≥ 6000 V_{rms} for one second (leakage detection current limit, I_{I-O} ≤ 5 µA).

chanhvinh.com

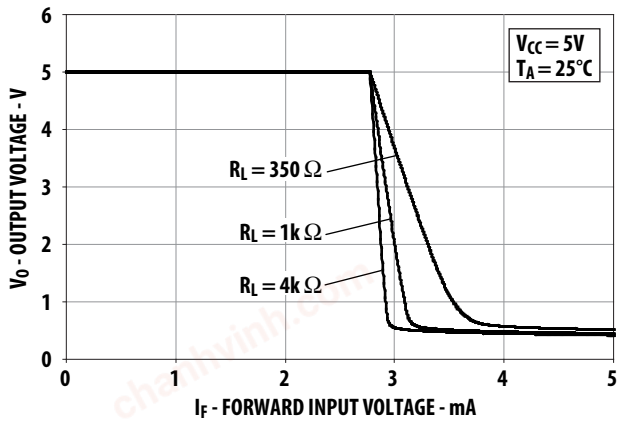


Figure 1. Typical output voltage vs. forward input voltage current.

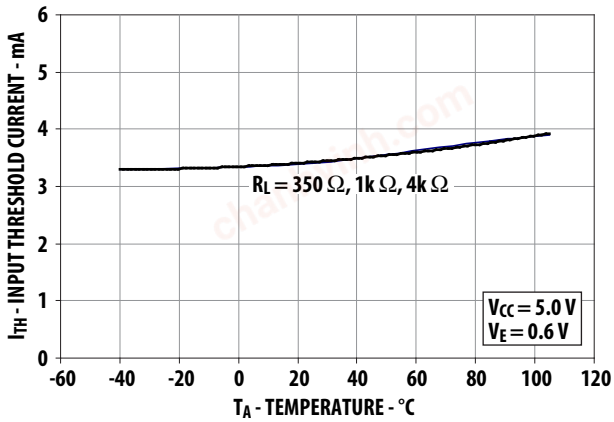


Figure 2. Typical input threshold current vs. temperature.

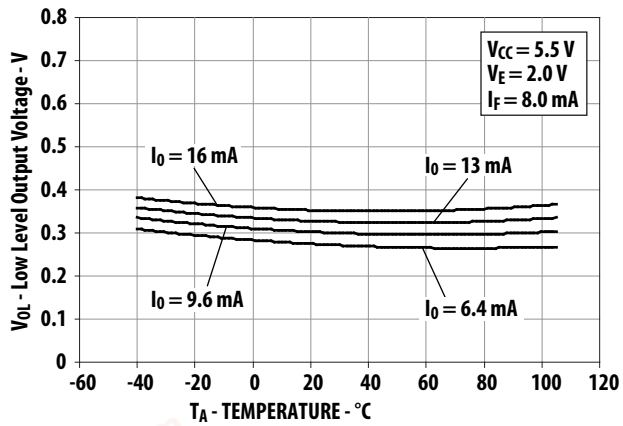


Figure 3. Typical low level output voltage vs. temperature.

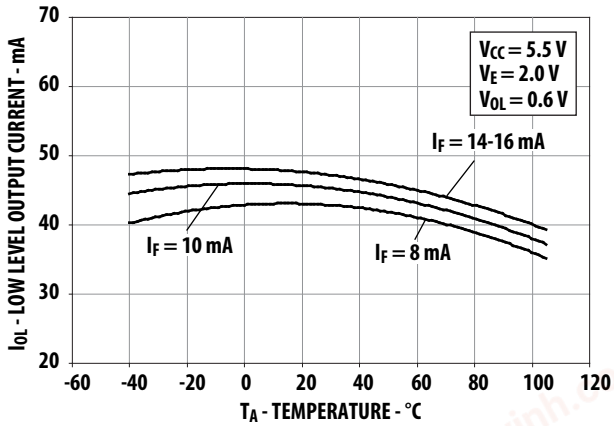


Figure 4. Typical low level output current vs. temperature.

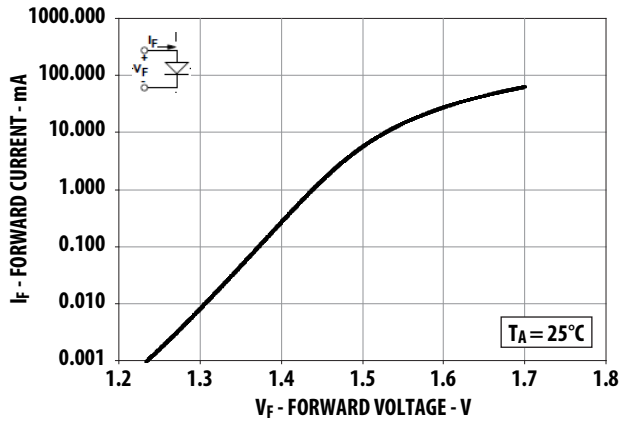


Figure 5. Typical input diode forward characteristic.

chanhvinh.com

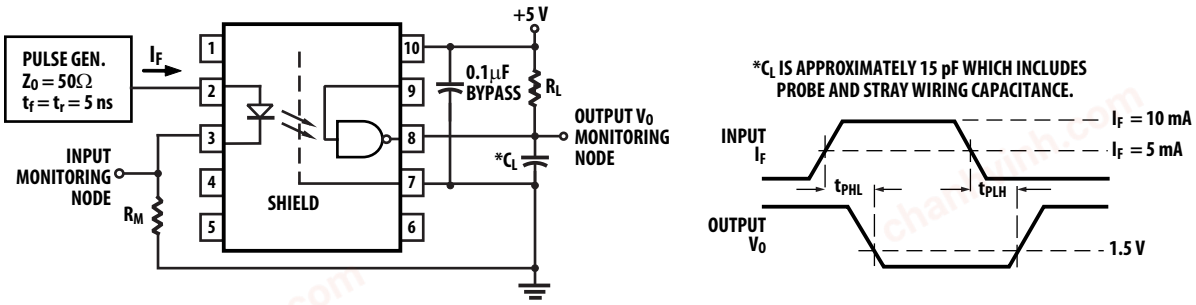


Figure 6. Test circuit for t_{PHL} and t_{PLH}

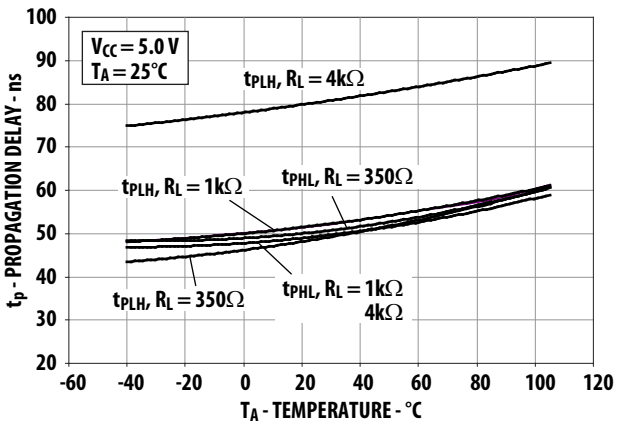


Figure 7. Typical propagation delay vs. temperature.

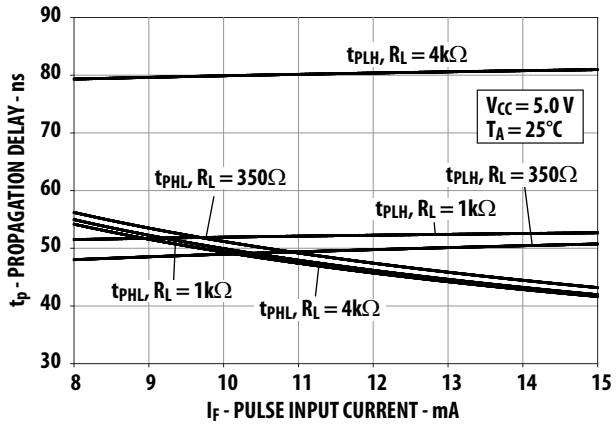


Figure 8. Typical propagation delay vs. pulse input current.

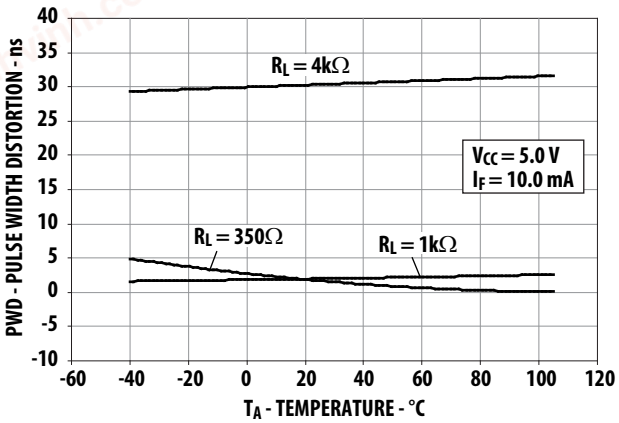


Figure 9. Typical pulse width distortion vs. temperature.

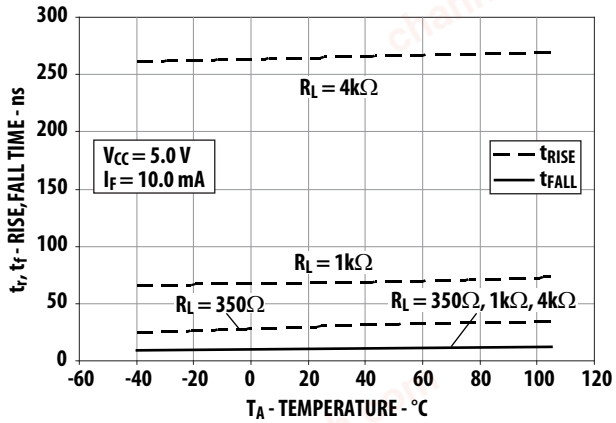
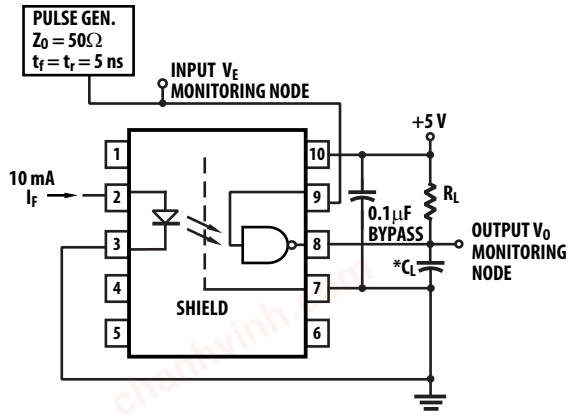
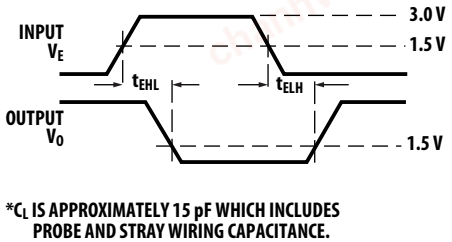


Figure 10. Typical rise and fall time vs. temperature.

chanhvinh.com





*C_L IS APPROXIMATELY 15 pF WHICH INCLUDES PROBE AND STRAY WIRING CAPACITANCE.

Figure 11. Test circuit for t_{EHL} and t_{ELH}.

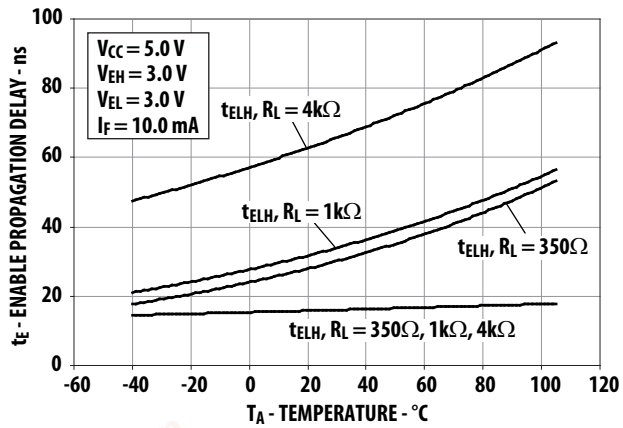


Figure 12. Typical enable propagation delay vs. temperature.

chanhvinh.com

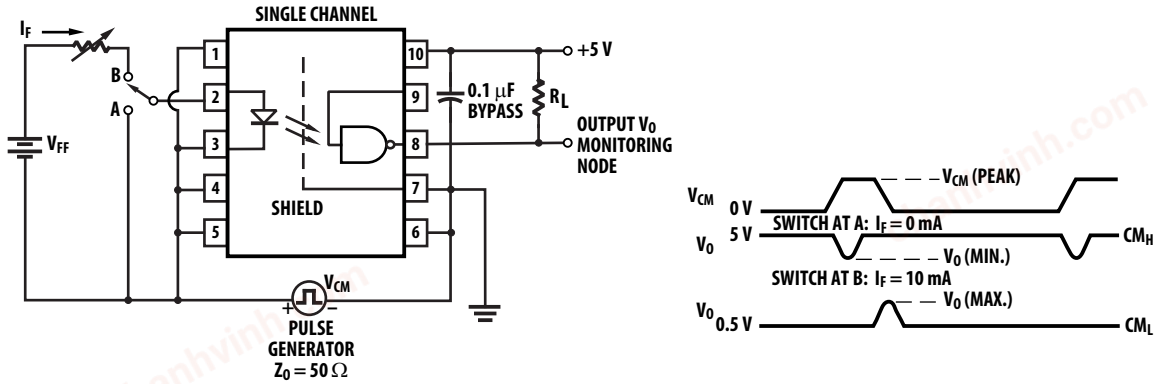


Figure 13. Test circuit for common mode transient immunity and typical waveforms.

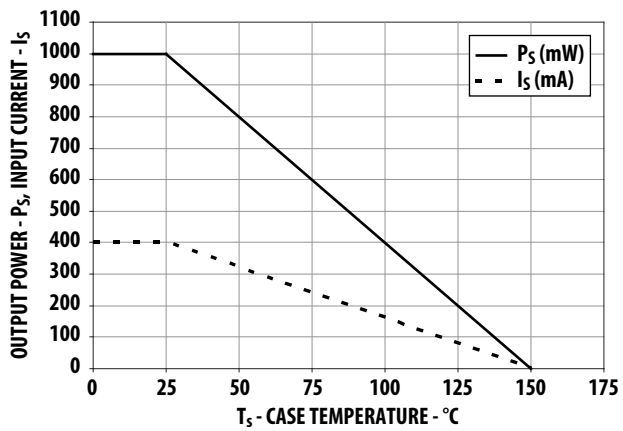


Figure 14. Thermal derating curve, dependence of safety limiting value with case temperature per IEC/EN/DIN EN60747-5-5.

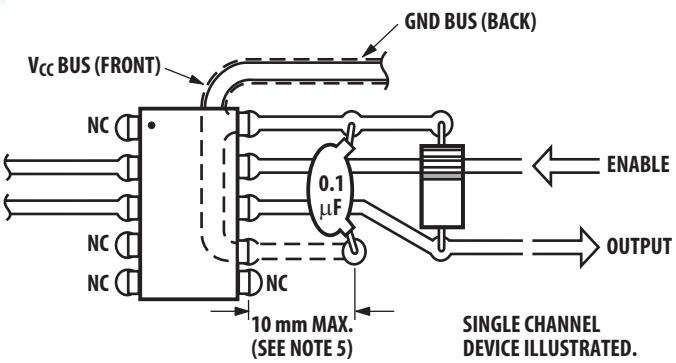


Figure 15. Recommended printed circuit board layout.

For product information and a complete list of distributors, please go to our web site: **www.avagotech.com**

Avago, Avago Technologies, and the A logo are trademarks of Avago Technologies in the United States and other countries.
Data subject to change. Copyright © 2005-2013 Avago Technologies. All rights reserved.
AV02-2457EN - September 13, 2013